

Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

E·XFI

Product Status	Obsolete
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	768B (512 x 12)
Program Memory Type	ОТР
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	2.5V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	20-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16lc54ct-04i-ss

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Pin Diagrams



Device Differences

Device	Voltage Range	Oscillator Selection (Program)	Oscillator	Process Technology (Microns)	ROM Equivalent	MCLR Filter
PIC16C54	2.5-6.25	Factory	See Note 1	1.2	PIC16CR54A	No
PIC16C54A	2.0-6.25	User	See Note 1	0.9	—	No
PIC16C54C	2.5-5.5	User	See Note 1	0.7	PIC16CR54C	Yes
PIC16C55	2.5-6.25	Factory	See Note 1	1.7	—	No
PIC16C55A	2.5-5.5	User	See Note 1	0.7	—	Yes
PIC16C56	2.5-6.25	Factory	See Note 1	1.7	—	No
PIC16C56A	2.5-5.5	User	See Note 1	0.7	PIC16CR56A	Yes
PIC16C57	2.5-6.25	Factory	See Note 1	1.2	—	No
PIC16C57C	2.5-5.5	User	See Note 1	0.7	PIC16CR57C	Yes
PIC16C58B	2.5-5.5	User	See Note 1	0.7	PIC16CR58B	Yes
PIC16CR54A	2.5-6.25	Factory	See Note 1	1.2	N/A	Yes
PIC16CR54C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR56A	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR57C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR58B	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes

Note 1: If you change from this device to another device, please verify oscillator characteristics in your application.

Note: The table shown above shows the generic names of the PIC16C5X devices. For device varieties, please refer to Section 2.0.

6.4 **OPTION Register**

The OPTION Register is a 6-bit wide, write-only register which contains various control bits to configure the Timer0/WDT prescaler and Timer0.

By executing the OPTION instruction, the contents of the W Register will be transferred to the OPTION Register. A RESET sets the OPTION<5:0> bits.

REGISTER 6-2: OPTION REGISTER

U-0	U-0	W-1	W-1	W-1	W-1	W-1	W-1
_	_	TOCS	TOSE	PSA	PS2	PS1	PS0
bit 7							bit 0

- bit 7-6: Unimplemented: Read as '0'
- bit 5: **TOCS**: Timer0 clock source select bit
 - 1 = Transition on T0CKI pin
 - 0 = Internal instruction cycle clock (CLKOUT)
- bit 4: **TOSE**: Timer0 source edge select bit
 - 1 = Increment on high-to-low transition on T0CKI pin
 - 0 = Increment on low-to-high transition on T0CKI pin
- bit 3: **PSA**: Prescaler assignment bit
 - 1 = Prescaler assigned to the WDT
 - 0 = Prescaler assigned to Timer0

bit 2-0: **PS<2:0>:** Prescaler rate select bits

Bit Value	Timer0 Rate	WDT Rate
000	1:2	1:1
001	1:4	1:2
010	1:8	1:4
011	1:16	1:8
100	1:32	1:16
101	1:64	1:32
110	1 : 128	1:64
111	1:256	1:128

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented b	it, read as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

NOTES:

ADDWF	Add W	and f		
Syntax:	[label] A	DDWF	f,d	
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$			
Operation:	(W) + (f)	\rightarrow (dest)		
Status Affected:	C, DC, Z			
Encoding:	0001	11df	ffff	
Description:	and regis	ster 'f'. If 'o in the W sult is sto	of the W r d' is 0 the register. I red back	result f 'd' is
Words:	1			
Cycles:	1			
Example:	ADDWF	TEMP_RE	CG, 0	
Before Instr W TEMP_I After Instruc W TEMP_F	= REG = ction =	0x17 0xC2 0xD9 0xC2		

ANDWF	AND W with f
Syntax:	[label] ANDWF f,d
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$
Operation:	(W) .AND. (f) \rightarrow (dest)
Status Affected:	Z
Encoding:	0001 01df ffff
Description:	The contents of the W register are AND'ed with register 'f'. If 'd' is 0 the result is stored in the W regis- ter. If 'd' is '1' the result is stored back in register 'f'.
Words:	1
Cycles:	1
Example:	ANDWF TEMP_REG, 1
Before Instru W TEMP_ After Instruc W TEMP_	= 0x17 REG = 0xC2 tion = 0x17

ANDLW	AND literal with W
Syntax:	[<i>label</i>] ANDLW k
Operands:	$0 \le k \le 255$
Operation:	(W).AND. (k) \rightarrow (W)
Status Affected:	Z
Encoding:	1110 kkkk kkkk
Description:	The contents of the W register are AND'ed with the eight-bit literal 'k'. The result is placed in the W regis- ter.
Words:	1
Cycles:	1
Example:	ANDLW H'5F'
Before Instru W = After Instruc W =	0xA3

BCF	Bit Clea	r f			
Syntax:	[label]	[label] BCF f,b			
Operands:		$\begin{array}{l} 0 \leq f \leq 31 \\ 0 \leq b \leq 7 \end{array}$			
Operation:	$0 \rightarrow (f < b$	>)			
Status Affected:	None				
Encoding:	0100	bbbf	ffff		
Description:	Bit 'b' in	register 'f'	is cleared.		
Words:	1				
Cycles:	1				
Example:	BCF	FLAG_RE	IG, 7		
Before Instru FLAG_F After Instruct	0xC7				
FLAG_F	REG =	0x47			

GOTO	Unconditional Branch		
Syntax:	[label]	GOTO	k
Operands:	$0 \le k \le 5^{-1}$	11	
Operation:	$k \rightarrow PC < STATUS$,	PC<10:9>
Status Affected:	None		
Encoding:	101k	kkkk	kkkk
Description:	GOTO is an unconditional branch. The 9-bit immediate value is loaded into PC bits <8:0>. The upper bits of PC are loaded from STATUS<6:5>. GOTO is a two- cycle instruction.		
Words:	1		
Cycles:	2		
Example:	GOTO THERE		
After Instruct PC =	ion address	G (THER	E)

INCF	Increment f
Syntax:	[label] INCF f,d
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$
Operation:	(f) + 1 \rightarrow (dest)
Status Affected:	Z
Encoding:	0010 10df ffff
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.
Words:	1
Cycles:	1
Example:	INCF CNT, 1
Before Instru CNT Z After Instruct CNT Z	= 0xFF = 0

INCFSZ	Increment f, Skip if 0
Syntax:	[label] INCFSZ f,d
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$
Operation:	(f) + 1 \rightarrow (dest), skip if result = 0
Status Affected:	None
Encoding:	0011 11df ffff
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'. If the result is 0, then the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a two- cycle instruction.
Words:	1
Cycles:	1(2)
Example:	HERE INCFSZ CNT, 1 GOTO LOOP CONTINUE • • •
Before Instru PC After Instruc	= address (HERE)
CNT if CNT PC if CNT PC	<pre>= CNT + 1; = 0, = address (CONTINUE); ≠ 0, = address (HERE +1)</pre>

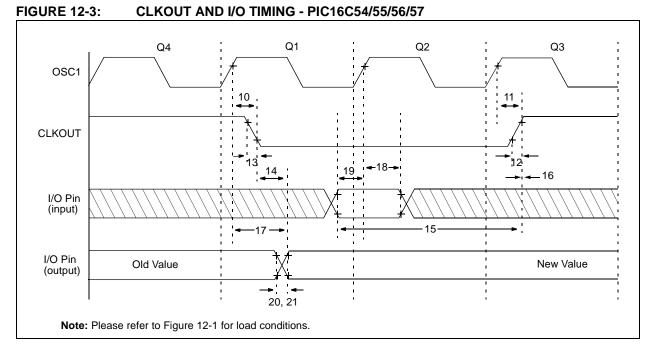


TABLE 12-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Characteristics		$\begin{array}{llllllllllllllllllllllllllllllllllll$						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units		
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	—	15	30**	ns		
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	_	15	30**	ns		
12	TckR	CLKOUT rise time ⁽¹⁾		5.0	15**	ns		
13	TckF	CLKOUT fall time ⁽¹⁾	—	5.0	15**	ns		
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾			40**	ns		
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	_	_	ns		
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*	_	_	ns		
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	_		100*	ns		
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—		ns		
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns		
20	TioR	Port output rise time ⁽²⁾	—	10	25**	ns		
21	TioF	Port output fall time ⁽²⁾	—	10	25**	ns		

* These parameters are characterized but not tested.

** These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 12-1 for load conditions.

13.4 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions	
D030	VIL	Input Low Voltage						
		I/O ports	Vss	_	0.15 Vdd	V	Pin at hi-impedance	
		MCLR (Schmitt Trigger)	Vss	—	0.15 Vdd	V		
		T0CKI (Schmitt Trigger)	Vss	—	0.15 VDD	V		
		OSC1 (Schmitt Trigger)	Vss		0.15 VDD	V	RC mode only ⁽³⁾	
		OSC1	Vss		0.3 Vdd	V	XT, HS and LP modes	
D040	Vін	Input High Voltage						
		I/O ports	0.45 Vdd	—	Vdd	V	For all VDD ⁽⁴⁾	
		I/O ports	2.0	—	Vdd	V	$4.0V < VDD \le 5.5V^{(4)}$	
		I/O ports	0.36 VDD	—	Vdd	V	VDD > 5.5V	
		MCLR (Schmitt Trigger)	0.85 VDD	—	Vdd	V		
		T0CKI (Schmitt Trigger)	0.85 VDD	—	Vdd	V		
		OSC1 (Schmitt Trigger)	0.85 VDD	—	Vdd	V	RC mode only ⁽³⁾	
		OSC1	0.7 Vdd		Vdd	V	XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—		V		
D060	lı∟	Input Leakage Current ^(1,2)					For V DD ≤ 5.5V :	
		I/O ports	-1.0	0.5	+1.0	μA	$VSS \leq VPIN \leq VDD$,	
							pin at hi-impedance	
		MCLR	-5.0		_	μA	VPIN = VSS + 0.25V	
		MCLR		0.5	+5.0	μΑ	VPIN = VDD	
		TOCKI	-3.0	0.5	+3.0	μΑ	$VSS \leq VPIN \leq VDD$	
		OSC1	-3.0	0.5	+3.0	μA	$VSS \leq VPIN \leq VDD$,	
						•	XT, HS and LP modes	
D080	Vol	Output Low Voltage						
		I/O ports	_	_	0.6	V	IOL = 8.7 mA, VDD = 4.5V	
		OSC2/CLKOUT	_	_	0.6	V	IOL = 1.6 mA, VDD = 4.5 V,	
							RC mode only	
D090	Vон	Output High Voltage ⁽²⁾						
		I/O ports	Vdd - 0.7	—	—	V	IOH = −5.4 mA, VDD = 4.5\	
		OSC2/CLKOUT	Vdd - 0.7	—	—	V	IOH = -1.0 mA, VDD = 4.5 V RC mode only	

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

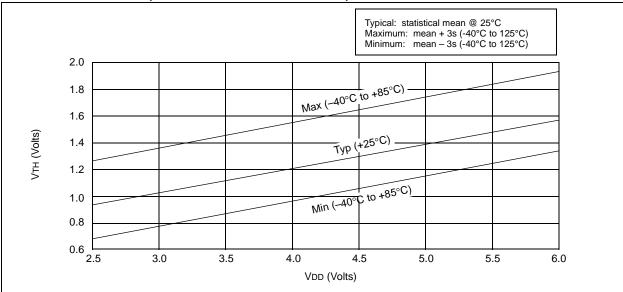
Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

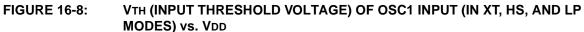
2: Negative current is defined as coming out of the pin.

3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

4: The user may use the better of the two specifications.

FIGURE 16-7: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS - VDD





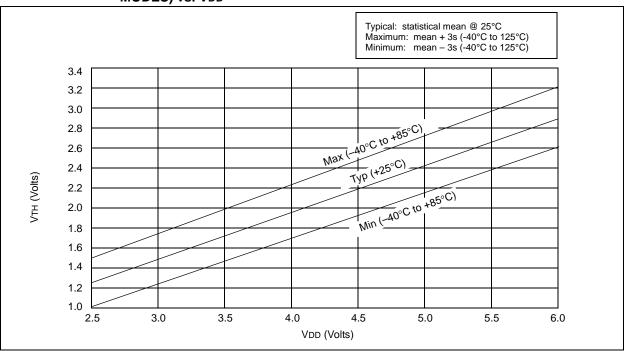
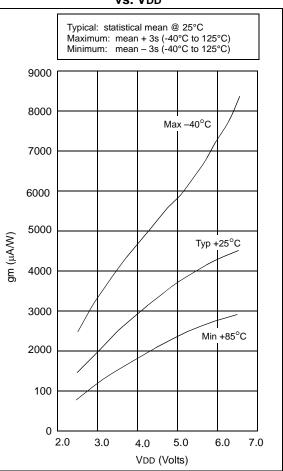




FIGURE 16-17: TRANSCONDUCTANCE (gm) OF HS OSCILLATOR vs. VDD



17.4 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	pS	
Т		
F	Frequency	T Time
Lowe	rcase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	rcase letters and their meanings:	
S		
F	Fall	P Period
н	High	R Rise
I	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

FIGURE 17-5: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/C58B/CR58B-04, 20



17.5 Timing Diagrams and Specifications

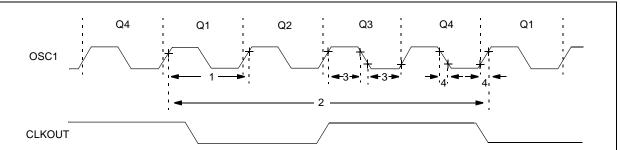


FIGURE 17-6: EXTERNAL CLOCK TIMING - PIC16C5X, PIC16CR5X

TABLE 17-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X, PIC16CR5X

AC Characteristics		$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array}$							
Param No. Symbol		Characteristic	Min	Тур†	Max	Units	Conditions		
	Fosc	External CLKIN Frequency ⁽¹⁾	DC	_	4.0	MHz	XT osc mode		
			DC	—	4.0	MHz	HS osc mode (04)		
			DC	—	20	MHz	HS osc mode (20)		
			DC	—	200	kHz	LP OSC mode		
		Oscillator Frequency ⁽¹⁾	DC	—	4.0	MHz	RC osc mode		
			0.45	—	4.0	MHz	XT osc mode		
			4.0	—	4.0	MHz	HS osc mode (04)		
			4.0	—	20	MHz	HS osc mode (20)		
			5.0	—	200	kHz	LP osc mode		
1	Tosc	External CLKIN Period ⁽¹⁾	250	—	—	ns	XT osc mode		
			250	—	—	ns	HS osc mode (04)		
			50	—	—	ns	HS osc mode (20)		
			5.0	—	—	μS	LP osc mode		
		Oscillator Period ⁽¹⁾	250	—	—	ns	RC osc mode		
			250	—	2,200	ns	XT osc mode		
			250	—	250	ns	HS osc mode (04)		
			50	—	250	ns	HS osc mode (20)		
			5.0	—	200	μS	LP OSC mode		

* These parameters are characterized but not tested.

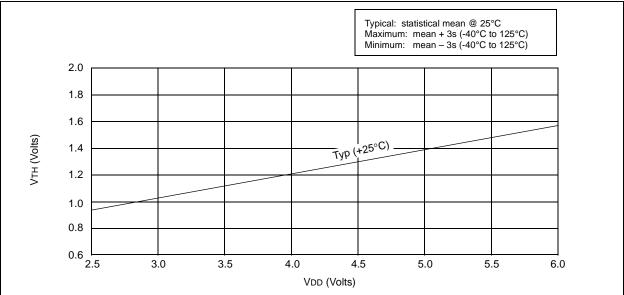
† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

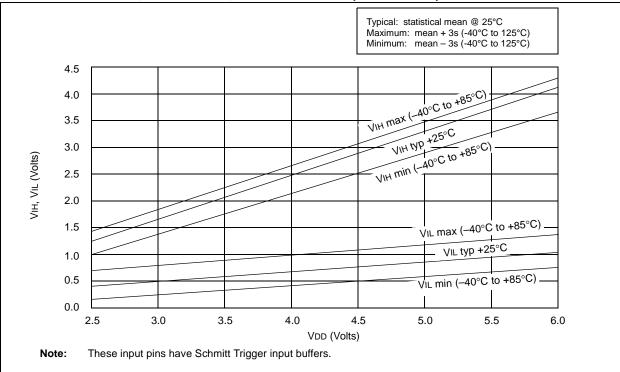
When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.









© 1997-2013 Microchip Technology Inc.

PIC16C5X

FIGURE 18-10: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (IN XT, HS AND LP MODES) vs. VDD







19.0 ELECTRICAL CHARACTERISTICS - PIC16LC54C 40MHz

Absolute Maximum Ratings^(†)

Ambient temperature under bias	–55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to VSS	0 to +7.5V
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss	–0.6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into Vod pin	
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, liк (Vi <0 or Vi > VDD)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O (Port A, B or C)	50 mA
Max. output current sunk by a single I/O (Port A, B or C)	50 mA
Note 1: Power dissipation is calculated as follows: Pdis = VDD x {IDD - \sum IOH} + \sum {(VDD-VOH)	x IOH} + Σ (Vol x Iol)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

19.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)⁽¹⁾

			Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O Ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	Vss Vss Vss Vss		0.8 0.15 VDD 0.15 VDD 0.2 VDD	> > > > > >	4.5V <vdd <math="">\leq 5.5V HS, 20 MHz \leq Fosc \leq 40 MHz</vdd>	
D040	Viн	Input High Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	2.0 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.8 Vdd		Vdd Vdd Vdd Vdd	V V V V	$4.5V < VDD \le 5.5V$ HS, 20 MHz \le Fosc \le 40 MHz	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	_	_	V		
D060	lı∟	Input Leakage Current ^(2,3) I/O ports MCLR MCLR T0CKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0 —	μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS +0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, HS	
D080	Vol	Output Low Voltage I/O ports		_	0.6	V	Iol = 8.7 mA, Vdd = 4.5V	
D090	Vон	Output High Voltage⁽³⁾ I/O ports	Vdd - 0.7	_	_	V	Іон = -5.4 mA, Vdd = 4.5V	

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Device operation between 20 MHz to 40 MHz requires the following: VDD between 4.5V to 5.5V, OSC1 pin externally driven, OSC2 pin not connected and HS oscillator mode and commercial temperatures. For operation between DC and 20 MHz, See Section 17.3.

2: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

3: Negative current is defined as coming out of the pin.

19.3 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	pS	
Т		
F	Frequency	T Time
Lowe	ercase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	ercase letters and their meanings:	
S		
F	Fall	P Period
н	High	R Rise
Ι	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

FIGURE 19-2: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/C55A/C56A/C57C/C58B-40













TABLE 20-1: INPUT CAPACITANCE

Pin	Typical Capacitance (pF)				
FIII	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
тоскі	3.2	2.8			

All capacitance values are typical at 25° C. A part-to-part variation of ±25% (three standard deviations) should be taken into account.



21.0 PACKAGING INFORMATION

21.1 Package Marketing Information

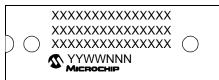
18-Lead PDIP



28-Lead Skinny PDIP (.300")



28-Lead PDIP (.600")



18-Lead SOIC



28-Lead SOIC

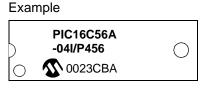


20-Lead SSOP



28-Lead SSOP

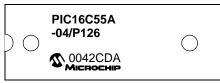




Example



Example



Example



Example



Example

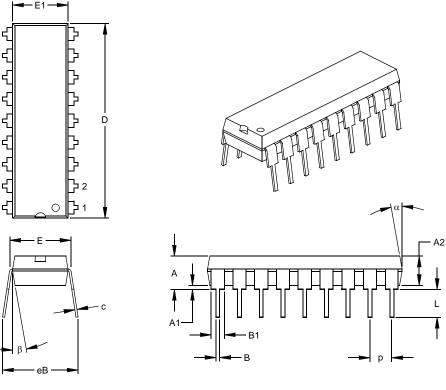


Example



18-Lead Plastic Dual In-line (P) – 300 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		18			18		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.890	.898	.905	22.61	22.80	22.99	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

* Controlling Parameter § Significant Characteristic

Notes:

n

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-007